## **DECLARATION**

AS THE BELOW NAMED INVENTORS, We hereby declare that:

Our residence, post office address and citizenship are as stated next to our name.

I believe that I am the original, first and sole (if only one name is listed below), or an original, first and joint inventor (if plural names are listed below), of the subject matter which is claimed and for which a patent is sought on the invention entitled:

## TITLE: METHOD AND STRUCTURE FOR REDUCING GATE LEAKAGE AND THRESHOLD VOLTAGE FLUCTUATION IN MEMORY CELLS

the specification of which either is attached hereto or indicates an attorney docket no. YOR920030292US1 (163-8), or:

was filed in the U.S. Patent & 7	Гrademark Office on a	nd assigned Serial No,
and (if applicable) was amende	ed on	······································
specification, including the claims the duty to disclose information application in accordance with T foreign priority benefits under application(s) for patent or inver which designated at least one co	s, as amended by any amendment which is material to patentabilitle 37 of the Code of Federal I Title 35, U.S. Code §119(a) ntor's certificate, or §365(a) of country other than the United Splications for patent or inventor	e contents of the above-identified treferred to above. I acknowledge ity and to the examination of this Regulations §1.56. I hereby claim o-(d) or §365(b) of any foreign any PCT international application tates, listed below and have also as certificate having a filing date
		Yes [ ]
No [ ] (Application Number)	(Country)	(Day/Month/Year filed)
		Yes [ ]
No [ ]		
(Application Number)	(Country)	(Day/Month/Year filed)

I hereby claim the benefit under Title 35, U.S. Code, §120 of any United States application(s), or §119(e) of any United States provisional application(s), or §365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application(s) in the manner provided by the first paragraph of Title 35, U.S. Code, §112, I acknowledge the duty to disclose information material to patentability as defined in Title 37, The Code of Federal Regulations, §1.56(a) which became available between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial Number)

(Filing Date)

(STATUS: patented, pending, abandoned)

(Application Serial Number)

(Filing Date)

(STATUS: patented, pending, abandoned)

I hereby appoint the following attorneys: Richard M. Ludwin (Reg. 33,010), Kevin M. Jordan (Reg. 40,277), Christopher A. Hughes (Reg. 26,914), John E. Hoel (Reg. 26, 279), Joseph C. Redmond, Jr. (Reg. 18,753), Douglas W. Cameron (Reg. 31, 596), Wan Yee Cheung (Reg. 42, 410), Thu Ann Dang (Reg. 41,544), Timothy M. Farrell (Reg. 37,321), Louis P. Herzberg (Reg. 41,500), Derek S. Jennings (Reg. 41,473), Stephen C. Kaufman (Reg. 29,551), Daniel P. Morris (Reg. 32,053), Allison Mortinger (Reg. 39,306), Louis J. Percello (Reg. 33,206), Robert M. Trepp (Reg. 25,933) and Gail H. Zarick (Reg. 43,303) each of them of INTERNATIONAL BUSINESS MACHINES CORPORATION, Thomas J. Watson Research Center, P.O. Box 218, Yorktown Heights, New York 10598; to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith and with any divisional, continuation, continuation-in-part, reissue or re-examination application, with full power of appointment and with full power to substitute an associate attorney or agent, and to receive all patents which may issue thereon, and request that all correspondence be addressed to:

James J. Bitetto, Esq. Keusey, Tutunjian & Bitetto, P.C. 14 Vanderventer Ave., Suite 128 Port Washington, New York 11050

Tel.: 516-883-3868

I HEREBY DECLARE that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under §1001 of Title 18 U.S. Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

FULL NAME OF ADDITIONAL INVENTOR: Azeez J. Bhavnagarwala
Citizenship: IN
Inventor's signature: Date: 7/22/03 Residence: Newtown, CT 06470
Post Office Address: 48 Farrell Road, Newtown, CT 06470
FULL NAME OF FIRST OR SOLE INVENTOR: Stephen V. Kosonocky Citizenship: US
Inventor's signature: Date: John 22, 2003 Residence: Wilton, CT 06897
Post Office Address: 21 Pin Oak Lane, Wilton, CT 06897

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S): Azeez J. Bhavnagarwala and Stephen V. Kosonocky

SERIAL NO.:

FILED:

FOR: METHOD AND STRUCTURE FOR REDUCING GATE LEAKAGE AND THRESHOLD VOLTAGE FLUCTUATION IN MEMORY CELLS

## ASSOCIATE POWER OF ATTORNEY

Please recognize JAMES J. BITETTO, Reg. No. 40,513; EDWIN H. KEUSEY, Reg. No. 34,361, JOHN G. TUTUNJIAN, Reg. No. 39,405; SUSAN PAIK, Reg. No. 46,347; and GASPARE J. RANDAZZO, Reg. No. 41,528; each of them of KEUSEY, TUTUNJIAN & BITETTO, P.C., 14 Vanderventer Ave., Suite 128, Port Washington, New York 11050 as associate attorneys in the above-mentioned application, with full power to prosecute said application, to make alterations and amendments therein, and to transact all business in the Patent and Trademark Office connected therewith.

Telephone calls should be made to James J. Bitetto by dialing (516) 883-3868.

All written communications are to be sent to

James J. Bitetto, Esq.

KEUSEY, TUTUNJIAN & BITETTO, P.C.

14 Vanderventer Ave., Suite 128

Port Washington, New York 11050.

International Business Machines

Corporation

T.J. Watson Research Center

Route 134 and Kitchawan Road

Yorktown Heights, New York 10598

Louis J. Percello

Registration No. 33,206

Attorney for Applicant(s)

D/ate